NEC's HIGH CMR, 10 MbpsOPEN COLLECTOR OUTPUT TYPE5-PIN SOP 3.3V HIGH-SPEED PHOTOCOUPLER

PS9121

DESCRIPTION

The PS9121 is an optically coupled high-speed, isolator containing a GaAlAs LED on the input side and a photodiode and a signal processing circuit on the output side on one chip.

PS9121 is specified high CMR, high CTR and pulse width distortion with operating temperature.

FEATURES

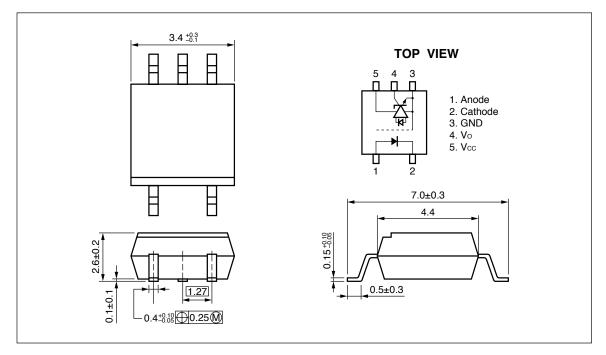
- Low Power Consumption (Vcc :3.3V)
- · Extended Vcc Operating Range to 5.5 V, Typical Performance Data included for reference
- High common mode transient immunity (CM_H, CM_L = $\pm 20 \text{ kV}/\mu \text{s TYP.}$)
- Pulse width distortion (| tPHL tPLH| = 35 ns MIN.)
- High-speed (10 Mbps)
- High isolation voltage (BV = 2 500 Vr.m.s.)
- Open collector output
- Ordering number of taping product: PS9121-F3, F4: 2 500 pcs/reel

APPLICATIONS

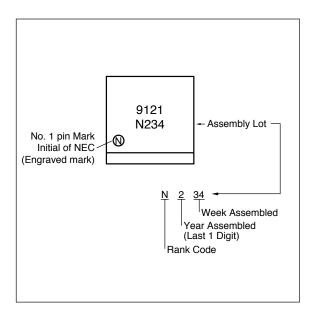
- · Measurement equipment
- PDP
- · FA Network

California Eastern Laboratories

PACKAGE DIMENSIONS (UNIT: mm)



MARKING



ORDERING INFORMATION

Part Number	Package	Packing Style	Application Part Number ^{*1}
PS9121	5-pin SOP	20 pcs (Tape 20 pcs cut)	PS9121
PS9121-F3		Embossed Tape 2 500 pcs/reel	
PS9121-F4			

*1 For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUN	RATINGS (T _A = 25°C, unless otherwise specified)
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Parameter		Symbol	Ratings	Unit
Diode	Forward Current ^{*1}	lf	30	mA
	Reverse Voltage	VR	5	v
Detector	Supply Voltage	Vcc	7	V
	Output Voltage	Vo	7	V
	Output Current	lo	25	mA
	Power Dissipation *2	Pc	40	mW
Isolation	Voltage *3	BV 2 500		Vr.m.s.
Operating Ambient Temperature		TA	–40 to +85	°C
Storage Temperature		Tstg	-55 to +125	°C

*1 Reduced to 0.3 mA/°C at $T_A = 25^{\circ}C$ or more.

*2 Applies to output pin Vo. Reduced to 1.5 mW/°C at $T_A = 65^{\circ}C$ or more.

*3 AC voltage for 1 minute at $T_A = 25^{\circ}C$, RH = 60% between input and output.

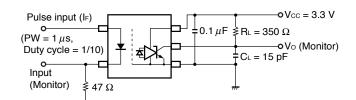
RECOMMENDED OPERATING CONDITIONS

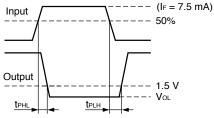
Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Low Level Input Voltage	VFL	0		0.8	V
High Level Input Current	Іғн	6.3	10	12.5	mA
Supply Voltage	Vcc	2.7		3.6	v
TTL (R∟ = 1 kΩ, loads)	N			5	
Pull-up resistor	R∟	330		4 k	Ω

ELECTRICAL CHARACTERISTICS (T_A = -40 to +85°C, unless otherwise specified)

Parameter		Symbol	Conditions		MIN.	TYP. ^{*1}	MAX.	Unit
Diode	Forward Voltage	VF	l⊧ = 10 mA, T₄ = 25°C		1.4	1.65	1.8	V
	Reverse Current		V _R = 3 V, T _A = 25°C				10	μA
	Terminal Capacitance	Ct	V = 0 V, f = 1 MHz, T _A = 25°C			30		pF
Detector High Level Output Current		Іон	Vcc = Vo = 3.3 V, V⊧ = 0.8 mV			1	80	μA
		Vcc = Vo = 5.5 V, V⊧ = 0.8 mV			1			
Low Level Output Voltage ^{*2}		Vol	Vcc = 3.3 V, I⊧ = 5 mA, Io∟ = 13 mA			0.2	0.6	v
			Vcc = 5.5 V, I⊧ = 5 mA, Io∟ = 13 mA			0.2		
	High Level Supply Current	Іссн	Iссн Vcc = 3.3 V , IF = 0 mA, Vo = open			4	7	μA
			Vcc = 5.5 V , I⊧ = 0 mA, Vo = open			5		
	Low Level Supply Current	lcc∟	Vcc = 3.3 V , I⊧ = 10 mA, Vo = open			7	10	
			Vcc = 5.5 V , I⊧ = 10 mA, Vo = open			9		
Coupled	Threshold Input Current	IFHL	$V_{\rm CC} = 3.3$ V, V ₀ = 0.8 V, R _L = 350 Ω			2.5	5	mA
	$(H \rightarrow L)$		$V_{CC} = 5 \text{ V}, \text{ Vo} = 0.8 \text{ V}, \text{ RL} = 350 \Omega$			2.5		
-	Isolation Resistance	R⊦o	$V_{I-O} = 1 \text{ kV}_{DC}, \text{ RH} = 40 \text{ to } 60\%,$ $T_A = 25^{\circ}\text{C}$		10 ¹¹			Ω
	Isolation Capacitance	Сю	V = 0 V, f = 1 MHz, T _A = 25°C			0.6		pF
	Propagation Delay Time	t₽HL		T _A = 25°C		43	75	ns
	$(H \rightarrow L)^{*3}$		Vcc = 3.3 V, RL = 350 Ω, IF = 7.5 mA				100	
			T _A = 25°C Vcc = 5 V, RL = 350 Ω, I⊧ = 7.5 mA		36			
	Propagation Delay Time	tрін		T _A = 25°C		46	75	
	$(L \rightarrow H)^{*3}$		$V_{CC} = 3.3 \text{ V}, \text{ R}_{L} = 350 \Omega, \text{ I}_{F} = 7.5 \text{ mA}$				100]
			T _A = 25°C			39		
			$V_{\text{CC}} = 5 \text{ V}, \text{R}_{\text{L}} = 350 \Omega, \text{I}_{\text{F}} = 7.5 \text{m}\text{A}$					
	Rise Time	tr	Vcc = 3.3 V, R∟ = 350 Ω, I⊧ = 7.5 mA			20		
			V_{CC} = 5 V, R_L = 350 Ω , I_F = 7.5 mA					
	Fall Time	tr	Vcc = 3.3 V, R∟ = 350 Ω, I⊧ = 7.5 mA			10		
			Vcc = 5 V, R∟ = 350 Ω, I⊧ = 7.5 mA					
	Pulse Width Distortion $ t_{PHL}-t_{PLH} $ (PWD) *3		Vcc = 3.3 V, R∟ = 35	0 Ω, I⊧ = 7.5 mA		3	35	
			Vcc = 5 V, R∟ = 350 Ω, I⊧ = 7.5 mA			3		
	Propagation Delay Skew	t ₽SK	Vcc = 3.3 V, R∟ = 350 Ω, I⊧ = 7.5 mA				40	
Transient High Leve Common I Transient	Common Mode Transient Immunity at High Level Output ^{*4}	СМн	RL = 350 Ω, TA = 25° Vo (min.) = 2 V, Vcm =		15	20		kV/µs
	Common Mode Transient Immunity at Low Level Output	CM∟	$ \begin{array}{l} R_{L} = 350 \ \Omega, \ T_{A} = 25^{\circ}C, \ I_{F} = 7.5 \ mA, \\ V_{O \ (MAX.)} = 0.8 \ V, \ V_{CM} = 1 \ kV \end{array} $		15	20		

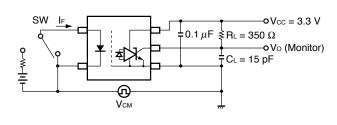
- *1 Typical values at T_A = 25°C
- *2 Because VoL of 2 V or more may be output when LED current input and when output supply of Vcc = 2.6 V or less, it is important to confirm the characteristics (operation with the power supply on and off) during design, before using this device.
- *3 Test circuit for propagation delay time

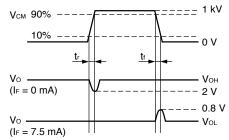




*4 Test circuit for common mode transient immunity

Remark C_L includes probe and stray wiring capacitance.



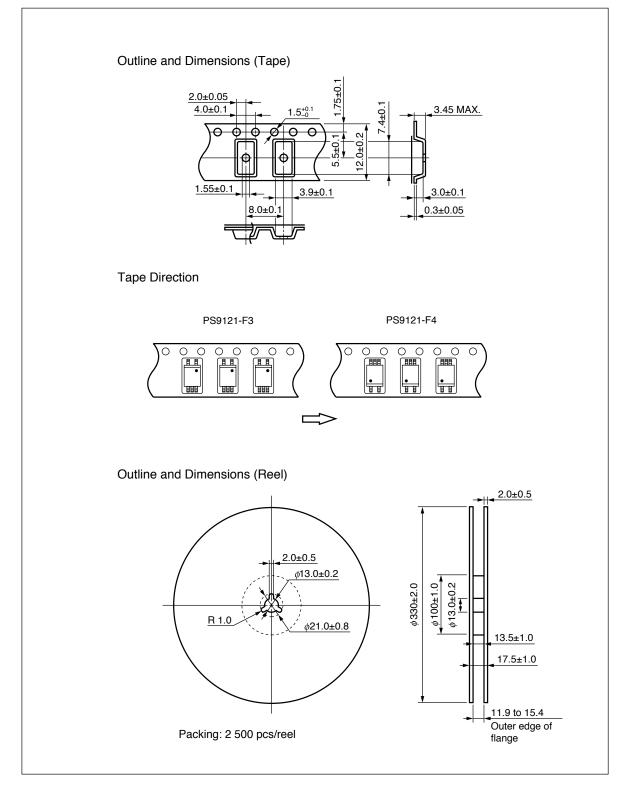


Remark CL includes probe and stray wiring capacitance.

USAGE CAUTIONS

- 1. This product is weak for static electricity by designed with high-speed integrated circuit so protect against static electricity when handling.
- 2. By-pass capacitor of 0.1 µF is used between Vcc and GND near device. Also, ensure that the distance between the leads of the photocoupler and capacitor is no more than 10 mm.
- 3. Avoid storage at a high temperature and high humidity.

TAPING SPECIFICATIONS (UNIT: mm)



1. Recommended soldering conditions

(1) Infrared reflow soldering

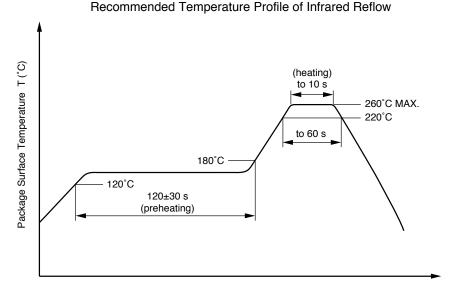
- · Peak reflow temperature 260°C or below (package surface temperature)
- · Time of peak reflow temperature

Time of temperature higher than 220°C

- Time to preheat temperature from 120 to 180°C
- · Number of reflows
- Flux

- 10 seconds or less
- 60 seconds or less
- 120±30 s Three

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)



Time (s)

(2) Wave soldering

Temperature

• Time

• Flux

- · Preheating conditions 120°C or below (package surface temperature)
- Number of times One (Allowed to be dipped in solder including plastic mold portion.)

10 seconds or less

260°C or below (molten solder temperature)

- Rosin flux containing small amount of chlorine (The flux with a maximum chlorine
 - content of 0.2 Wt% is recommended.)

(3) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collector-emitters at startup, the output side may enter the on state, even if the voltage is within the absolute maximum ratings.

Life Support Applications

These NEC products are not intended for use in life support devices, appliances, or systems where the malfunction of these products can reasonably be expected to result in personal injury. The customers of CEL using or selling these products for use in such applications do so at their own risk and agree to fully indemnify CEL for all damages resulting from such improper use or sale.

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